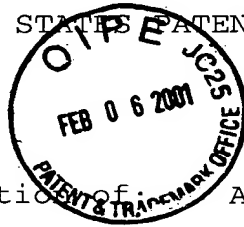


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



In re Application of Azam, Mizbahul et al.
Serial No.: 09/705,274
Filing Date: November 3, 2000
Group Art Unit: 2814
Examiner: TBD
Title: TRENCH GROWTH TECHNIQUES USING
SELECTIVE EPITAXY

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SIGNATURE

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Honorable Commissioner of Patents and Trademarks,
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SIR:

Response to Patent Application Filing Receipt

In response to the filing receipt of January 08, 2001,
an error in the name of the third named inventor has been

noted and applicants hereby request for name correction.
Please change the third named inventor from "Christopher J.
Glass" as is incorrectly stated in the filing receipt, to --
Christopher J. Gass--.

Respectfully submitted,

Azam, Mizbahul et al.

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Date: 1-30-01



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APPLICATION NUMBER	FILING DATE	GRP ART UNIT	FIL FEE REC'D	ATTY. DOCKET NO	DRAWINGS	TOT CLAIMS	IND CLAIMS
09/705,274	11/03/2000	2814	916	ONS00114	3	27	4

Robert D Atkins
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FILING RECEIPT



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Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Customer Service Center. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the PTO processes the reply to the Notice, the PTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Misbahul Azam, Gilbert, AZ ;
Jeffrey Pearse, Chandler, AZ ;
Christopher J. Glass, Tempe, AZ ;

Named is Glass

Continuing Data as Claimed by Applicant

Foreign Applications

If Required, Foreign Filing License Granted 01/05/2001

Title

Trench growth techniques using selective epitaxy

Preliminary Class

257

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